## NSN 5961-01-502-6480

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-502-6480 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.168 inches and 0.200 inches **Overall Height:** Between 0.091 inches and 0.103 inches Overall Width: Between 0.091 inches and 0.103 inches **End Application:** Aircraft, hornet f/a-18 (e/f); central processor **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 working peak reverse voltage **Current Rating Per Characteristic:** 2.00 amperes forward current, average and 20.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 bonding pad **Specification Data:** 81349-mil-prf-19500/585 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

Mil-std (military Standard):

Mil-prf-19500 spec.

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